



# CHENMKO ENTERPRISE CO.,LTD

**CH351H-30PT**

*Lead free devices*

**SURFACE MOUNT**  
**SCHOTTKY BARRIER DIODE**  
**VOLTAGE 30 Volts CURRENT 0.2 Ampere**

**APPLICATION**

- \* High speed switching for detection
- \* Voltage clamping
- \* Protection circuit

**FEATURE**

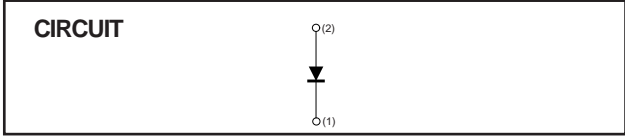
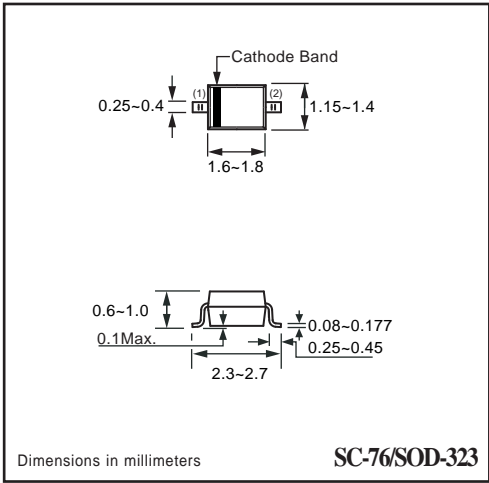
- \* Small surface mounting type. (SC-76/SOD-323)
- \* Low VF and low IR
- \* High reliability
- \* Low diode capacitance

**CONSTRUCTION**

- \* Silicon epitaxial planar

**MARKING**

- \* JU



**MAXIMUM RATINGS** ( At  $T_A = 25^{\circ}\text{C}$  unless otherwise noted )

RATINGS	SYMBOL	CH351H-30PT	UNITS
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	30	Volts
Maximum RMS Voltage	$V_{RMS}$	21	Volts
Maximum DC Blocking Voltage	$V_{DC}$	30	Volts
Maximum Average Forward Rectified Current	$I_o$	0.2	Amps
Repetitive Peak Forward Current at $T_P \leq 1 \text{ Sec } \phi \leq 0.5$	$I_{FRM}$	0.3	Amps
Non-Repetitive Peak Forward Current at $T_P < 10 \text{ mSec}$	$I_{FSM}$	0.6	Amps
Typical Junction Capacitance between Terminal (Note 1)	$C_J$	10.0	pF
Typical Thermal Resistance from junction to ambient	$R_{\theta JA}$	450	$^{\circ}\text{C/W}$
Maximum Operating and Storage Temperature Range	$T_{J,TSTG}$	-65 to +125	$^{\circ}\text{C}$

**ELECTRICAL CHARACTERISTICS** ( At  $T_A = 25^{\circ}\text{C}$  unless otherwise noted )

CHARACTERISTICS	SYMBOL	CH351H-30PT	UNITS
Maximum Instantaneous Forward Voltage	$I_F = 1\text{mA}$	300	mVolts
	$I_F = 10\text{mA}$	380	
	$I_F = 100\text{mA}$	550	
Maximum Average Reverse Current	$V_R = 25\text{V}$	2.0	uAmps
	$V_R = 30\text{V}$	10.0	

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 1.0 volts.  
 2. ESD sensitive product handling required.

## RATING CHARACTERISTIC CURVES ( CH351H-30PT )

FIG. 1 - FORWARD CHARACTERISTICS

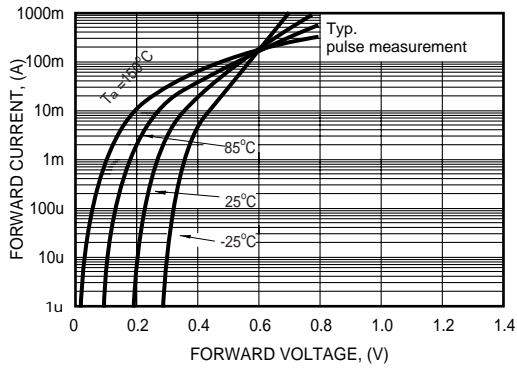


FIG. 2 - REVERSE CHARACTERISTICS

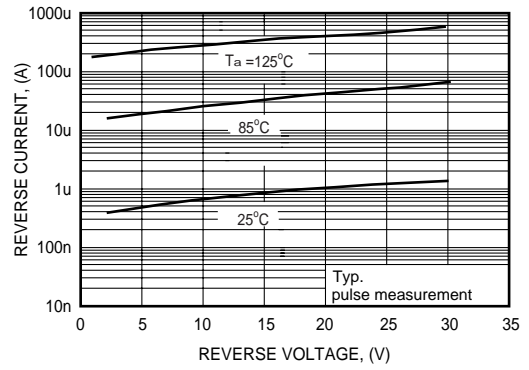


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

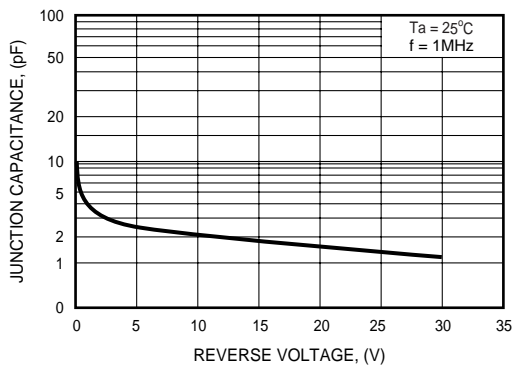


FIG. 4 - DIFFERENTIAL FORWARD RESISTANCE

